

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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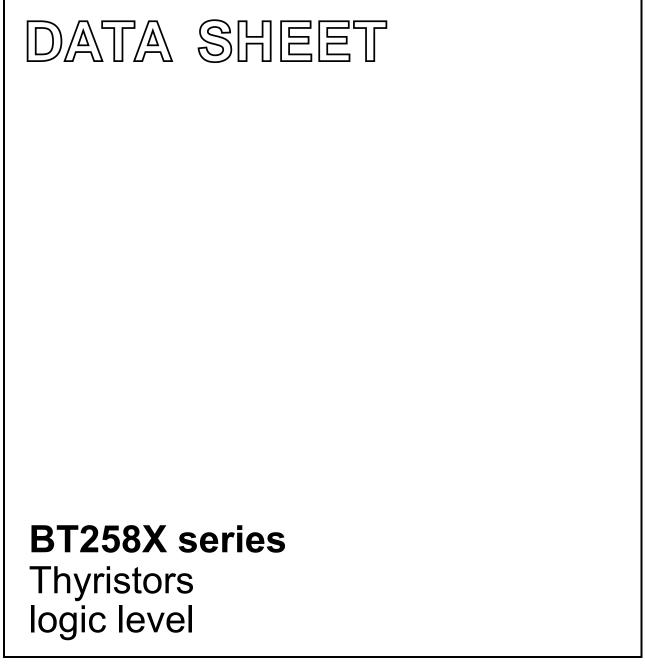
If you have any questions related to this document, please contact our nearest sales office via email or phone (details via <u>salesaddresses@ween-semi.com</u>).

Thank you for your cooperation and understanding,

WeEn Semiconductors



DISCRETE SEMICONDUCTORS



Product specification

October 2002



Thyristors logic level

GENERAL DESCRIPTION

Passivated, sensitive gate thyristors in a full pack, plastic envelope, intended for use in general purpose switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

DESCRIPTION

PINNING - SOT186A

cathode

anode

gate

PIN

1

2

3

case

C cas

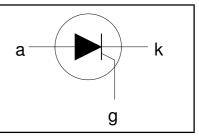
PIN CONFIGURATION

QUICK REFERENCE DATA

BT258X series

| SYMBOL | PARAMETER | MAX. | MAX. | MAX. | UNIT |
|---|---|-----------------------------|-----------------------------|-----------------------------|------------------|
| $\begin{array}{c} V_{\text{DRM}},\\ V_{\text{RRM}}\\ I_{\text{T(AV)}}\\ I_{\text{T(RMS)}}\\ I_{\text{TSM}} \end{array}$ | BT258X- Repetitive peak off-state voltages Average on-state current RMS on-state current Non-repetitive peak on-state current | 500R 500 5 8 75 | 600R 600 5 8 75 | 800R 800 5 8 75 | V A A A |

SYMBOL



LIMITING VALUES

isolated

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | | MAX. | | UNIT |
|--|---|---|--------------------|----------------------------------|--|---------------------|-----------------------|
| $V_{\text{drm}}, V_{\text{rrm}}$ | Repetitive peak off-state voltages | | - | -500R 500 ¹ | -600R 600 ¹ | -800R 800 | × |
| I _{T(AV)} I _{T(RMS)} I _{TSM} | Average on-state current RMS on-state current Non-repetitive peak on-state current | half sine wave; $T_{hs} \le 90$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge | - | | 5 8 | | A A |
| l²t dl _⊤ /dt | I ² t for fusing Repetitive rate of rise of on-state current after | $\begin{array}{l} t = 10 \text{ ms} \\ t = 8.3 \text{ ms} \\ t = 10 \text{ ms} \\ I_{TM} = 10 \text{ A}; I_G = 50 \text{ mA}; \\ dI_G/dt = 50 \text{ mA}/\mu s \end{array}$ | - - - | | 75 82 28 50 | | A A A²s A/µs |
| $\begin{matrix} I_{GM} \\ V_{RGM} \\ P_{GM} \\ P_{G(AV)} \\ T_{stg} \\ T_{j} \end{matrix}$ | triggering Peak gate current Peak reverse gate voltage Peak gate power Average gate power Storage temperature Operating junction temperature | over any 20 ms period | - - -40 - | | 2 5 0.5 150 125 ² | | o°o°≤≤< |

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s.

² Note: Operation above 110°C may require the use of a gate to cathode resistor of $1k\Omega$ or less.

Product specification

Thyristors logic level

BT258X series

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------------|--|---|------|------|------|------|
| V _{isol} | R.M.S. isolation voltage from all three terminals to external heatsink | f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree | - | - | 2500 | V |
| C _{isol} | Capacitance from T2 to external heatsink | f = 1 MHz | - | 10 | - | pF |

THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|---|--|------|--------------|-----------------|-------------------|
| R _{th j-hs} R _{th j-a} | Thermal resistance junction to heatsink Thermal resistance junction to ambient | with heatsink compound without heatsink compound in free air | - | - - 55 | 5.0 6.9 - | K/W K/W K/W |

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|---------------------------|---|------|------|------|------|
| I _{GT} | Gate trigger current | $V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$ | - | 50 | 200 | μA |
| | Latching current | $V_{\rm D}^{\rm B} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$ | - | 0.4 | 10 | mΑ |
| I I _H | Holding current | $V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$ | - | 0.3 | 6 | mA |
| İΫ _T | On-state voltage | $I_{T} = 16 A$ | - | 1.3 | 1.6 | V |
| V _{GT} | Gate trigger voltage | $\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$ | - | 0.4 | 1.5 | V |
| | | $V_{\rm D} = V_{\rm DBM(max)}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 110 \ ^{\circ}\text{C}$ | 0.1 | 0.2 | - | V |
| I _D , I _R | Off-state leakage current | $V_D^{D} = V_{DRM(max)}^{DRM(max)}; V_R = V_{RRM(max)}; T_j = 125 \text{°C}$ | - | 0.1 | 0.5 | mA |

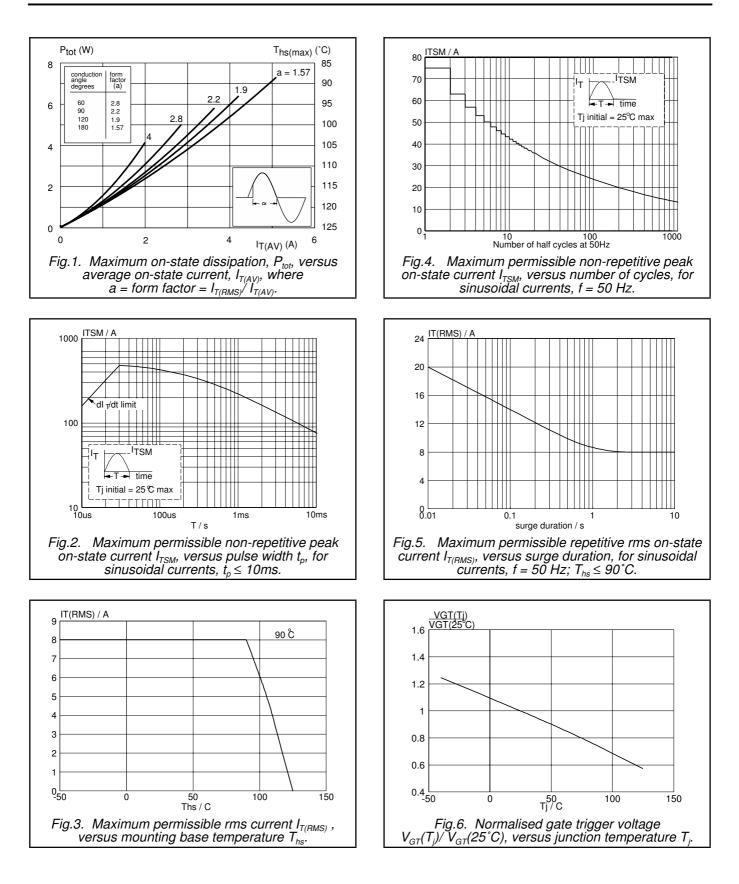
DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---------------------|--|---|------|------|------|------|
| dV _D /dt | Critical rate of rise of off-state voltage | $V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; $R_{GK} = 100 \Omega$ | 50 | 100 | - | V/µs |
| t _{gt} | Gate controlled turn-on | $I_{TM} = 10 \text{ A}; V_D = V_{DRM(max)}; I_G = 5 \text{ mA};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$ | - | 2 | - | μs |
| t _q | Circuit commutated turn-off time | | - | 100 | - | μs |

BT258X series

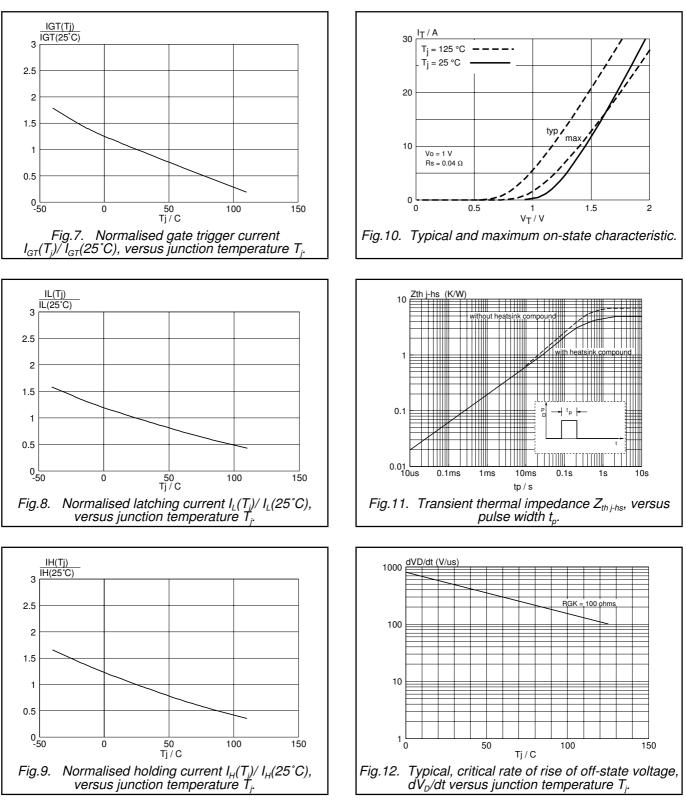
Thyristors logic level



Product specification

BT258X series

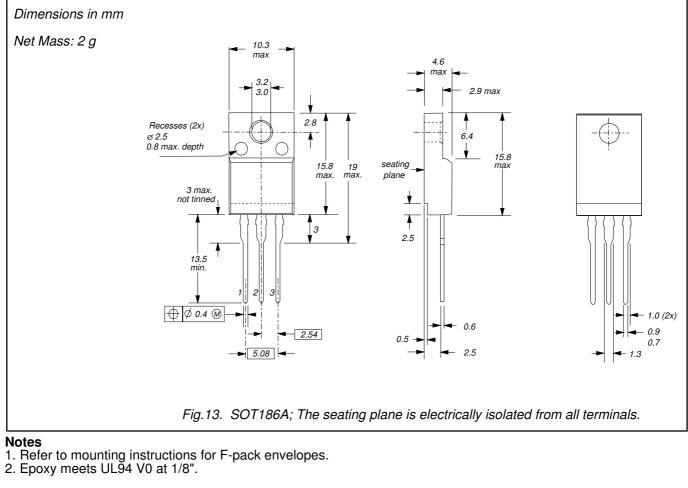
Thyristors logic level



Thyristors logic level

BT258X series

MECHANICAL DATA



Legal information

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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Contact information

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